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## FX3ASJ-3

# High-Speed Switching Use Pch Power MOS FET

REJ03G1436-0300 Rev.3.00 Dec 19, 2008

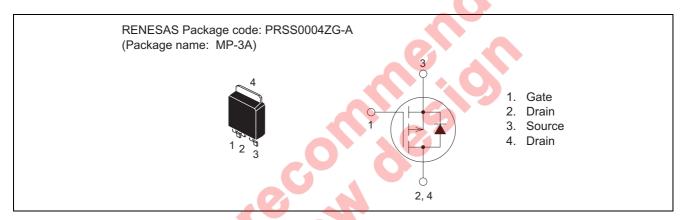
#### **Features**

 $\begin{array}{ll} \bullet & Drive\ voltage: 4\ V \\ \bullet & V_{DSS}: -150\ V \\ \bullet & r_{DS(ON)\,(max)}: 1.2\ \Omega \end{array}$ 

• Integrated Fast Recovery Diode (TYP.): 80 ns

#### **Outline**

 $I_{\rm D}$ : -3 A



### **Applications**

Motor control, Lamp control, Solenoid control, DC-DC converters, etc.

### **Maximum Ratings**

 $(Tc = 25^{\circ}C)$ 

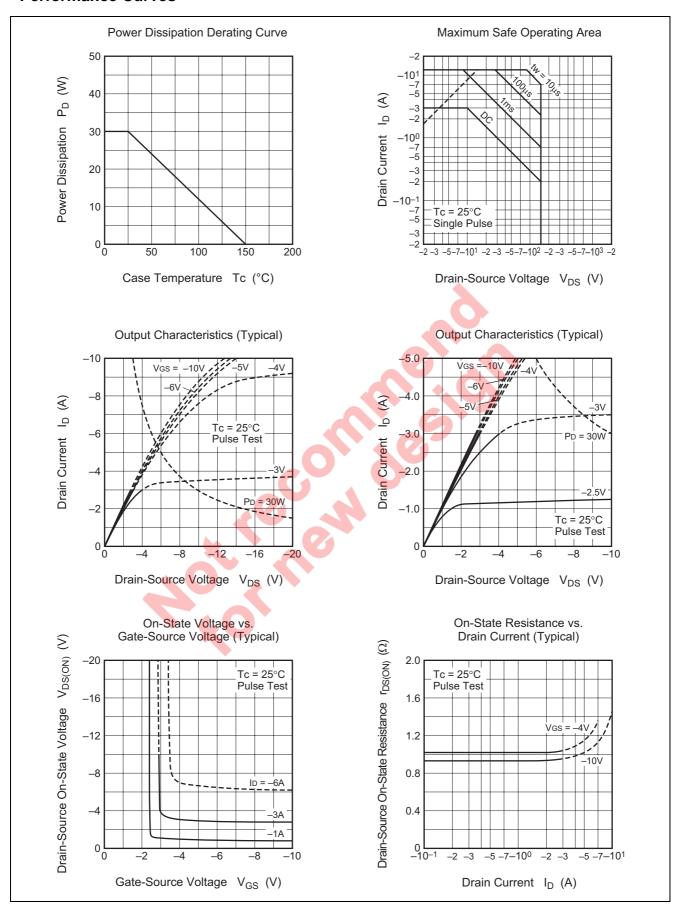
| Parameter                        | Symbol           | Ratings      | Unit | Conditions            |  |
|----------------------------------|------------------|--------------|------|-----------------------|--|
| Drain-source voltage             | V <sub>DSS</sub> | -150         | V    | V <sub>GS</sub> = 0 V |  |
| Gate-source voltage              | $V_{GSS}$        | ±20          | V    | $V_{DS} = 0 V$        |  |
| Drain current                    | I <sub>D</sub>   | -3           | Α    |                       |  |
| Drain current (Pulsed)           | I <sub>DM</sub>  | -12          | А    |                       |  |
| Avalanche drain current (Pulsed) | I <sub>DA</sub>  | -3           | А    | L = 100 μH            |  |
| Source current                   | Is               | -3           | Α    |                       |  |
| Source current (Pulsed)          | I <sub>SM</sub>  | -12          | А    |                       |  |
| Maximum power dissipation        | P <sub>D</sub>   | 30           | W    |                       |  |
| Channel temperature              | Tch              | - 55 to +150 | °C   |                       |  |
| Storage temperature              | Tstg             | - 55 to +150 | °C   |                       |  |
| Mass                             | _                | 0.32         | g    | Typical value         |  |

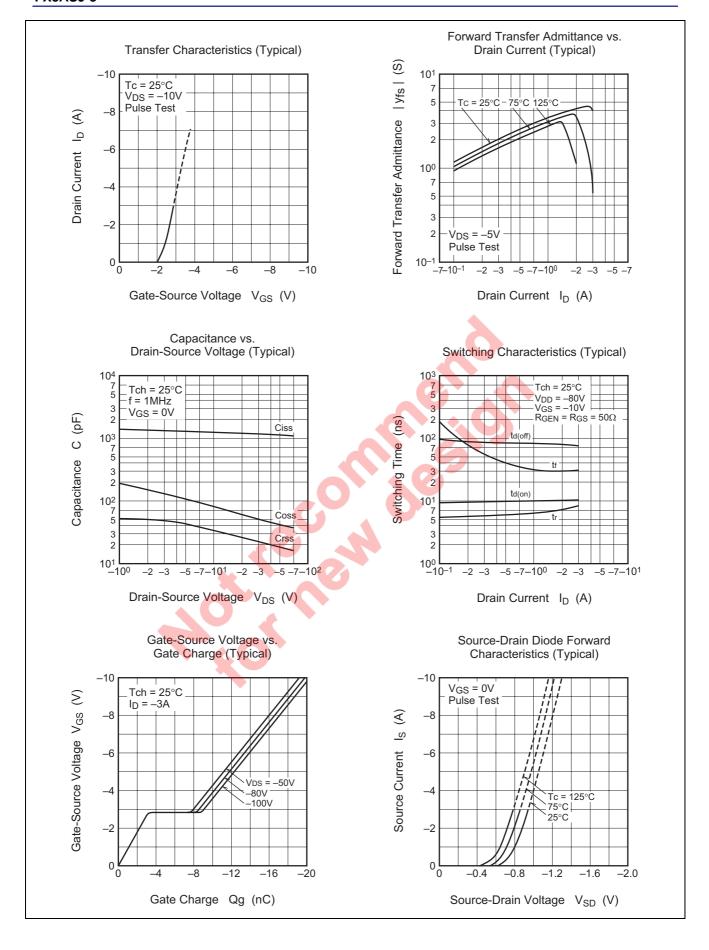
#### **Electrical Characteristics**

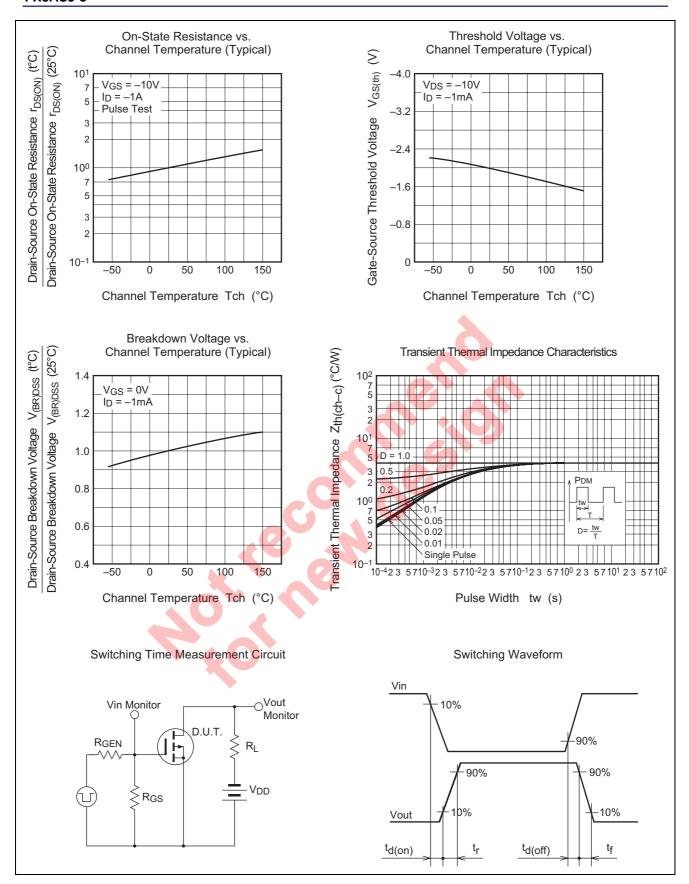
 $(Tch = 25^{\circ}C)$ 

| Parameter                                | Symbol                | Min  | Тур   | Max   | Unit | Test Conditions   |
|--|-----------------------|------|-------|-------|------|---|
| Drain-source breakdown voltage           | V <sub>(BR)DSS</sub>  | -150 | _     | _     | V    | $I_D = -1 \text{ mA}, V_{GS} = 0 \text{ V}$                   |
| Gate-source leakage current              | I <sub>GSS</sub>      | _    | _     | ±0.1  | μΑ   | $V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$             |
| Drain-source leakage current             | I <sub>DSS</sub>      | _    | _     | -0.1  | mA   | $V_{DS} = -150 \text{ V}, V_{GS} = 0 \text{ V}$               |
| Gate-source threshold voltage            | V <sub>GS(th)</sub>   | -1.3 | -1.8  | -2.3  | V    | $I_D = -1 \text{ mA}, V_{DS} = -10 \text{ V}$                 |
| Drain-source on-state resistance         | r <sub>DS(ON)</sub>   | _    | 0.93  | 1.20  | Ω    | $I_D = -1 A$ , $V_{GS} = -10 V$                               |
| Drain-source on-state resistance         | r <sub>DS(ON)</sub>   | _    | 1.02  | 1.32  | Ω    | $I_D = -1 A$ , $V_{GS} = -4 V$                                |
| Drain-source on-state voltage            | V <sub>DS(ON)</sub>   | _    | -0.93 | -1.20 | V    | $I_D = -1 A$ , $V_{GS} = -10 V$                               |
| Forward transfer admittance              | yfs                   | _    | 3.0   | _     | S    | $I_D = -1 A, V_{DS} = -5 V$                                   |
| Input capacitance                        | Ciss                  | _    | 1170  | _     | pF   | $V_{DS} = -10 \text{ V}, V_{GS} = 0 \text{ V},$               |
| Output capacitance                       | Coss                  | _    | 81    | _     | pF   | f = 1MHz  |
| Reverse transfer capacitance             | Crss                  | _    | 31    | _     | pF   |   |
| Turn-on delay time                       | t <sub>d(on)</sub>    | _    | 9     | _     | ns   | $V_{DD} = -80 \text{ V}, I_D = -1 \text{ A},$                 |
| Rise time                                | t <sub>r</sub>        | _    | 7     | _     | ns   | $V_{GS} = -10 \text{ V},$                                     |
| Turn-off delay time                      | t <sub>d(off)</sub>   | _    | 82    | _     | ns   | $R_{GEN} = R_{GS} = 50 \Omega$                                |
| Fall time                                | t <sub>f</sub>        | _    | 33    | _ (   | ns   |   |
| Source-drain voltage                     | V <sub>SD</sub>       | _    | -1.0  | -1.5  | V    | $I_S = -1 \text{ A}, V_{GS} = 0 \text{ V}$                    |
| Thermal resistance                       | R <sub>th(ch-c)</sub> | _    | _     | 4.17  | °C/W | Channel to case   |
| Reverse recovery time                    | t <sub>rr</sub>       | _    | 80    | (4)   | ns   | $I_S = -3 \text{ A}, d_{is}/d_t = 100 \text{ A}/\mu \text{s}$ |
| Thermal resistance Reverse recovery time | O T                   |      |       |       |      |   |
|  | •                     |      |       |       |      |   |

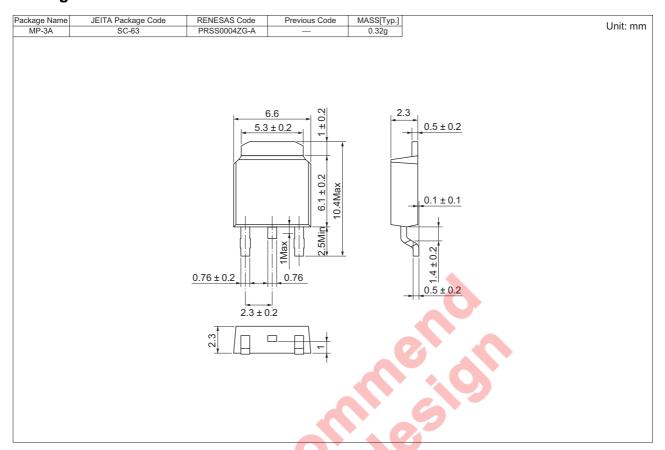
### **Performance Curves**







### **Package Dimensions**



### **Order Code**

| Lead form            | Standard packing        | Quantity | Standard order code                  | Standard order code example |  |
|----------------------|-------------------------|----------|--------------------------------------|-----------------------------|--|
| Surface-mounted type | Taping                  | 3000     | Type name – T +Direction (1 or 2) +3 | FX3ASJ-3-T13                |  |
| Surface-mounted type | Plastic Magazine (Tube) | 75       | Type name                            | FX3ASJ-3                    |  |

Note: Please confirm the specification about the shipping in detail.

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